

Features

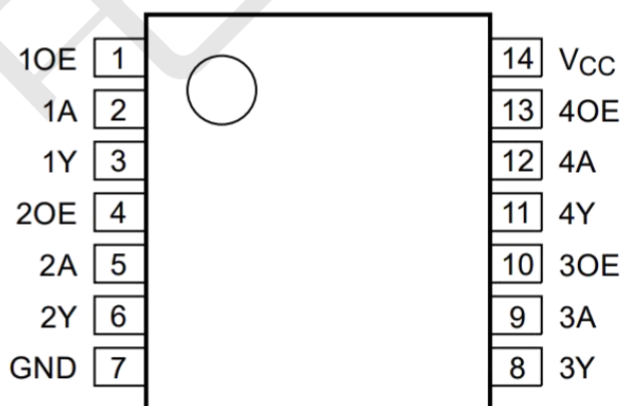
- Wide supply voltage range from 2.0 V to 5.5 V
- CMOS low power dissipation
- Overvoltage tolerant inputs to 5.5 V
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- ESD protection:
HBM ANSI/ESDA/JEDEC JS-00
Class 3A exceeds 6000 V
CDM ANSI/ESDA/JEDEC JS-002
Class C3 exceeds 2000 V
- I_{OFF} circuitry provides partial Power-down mode operation
- Complies with JEDEC standard:
JESD8-5 (2.3 V to 2.7 V)
JESD8C (2.7 V to 3.6 V)
JESD36 (4.5 V to 5.5 V)
- Packaging: TSSOP-14

General Description

The is a quad buffer/line driver with 3-state outputs controlled by the output enable inputs (nOE). A HIGH on nOE causes the outputs to assume a high impedance OFF-state. Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V environments.

Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times.

PIN CONFIGURATIONS (Top view)



TSSOP-14

PIN DESCRIPTION

PIN NO.	PIN NAME	DESCRIPTION	PIN NO.	PIN NAME	DESCRIPTION
1	1OE	Data enable input(active HIGH)	8	3Y	Data output
2	1A	Data input	9	3A	Data input
3	2Y	Data output	10	3OE	Data enable input(active HIGH)
4	2OE	Data enable input(active HIGH)	11	4Y	Data output
5	2A	Data input	12	4A	Data input
6	2Y	Data output	13	4OE	Data enable input(active HIGH)
7	GND	ground (0 V)	14	V _{CC}	supply voltage

Functional diagram

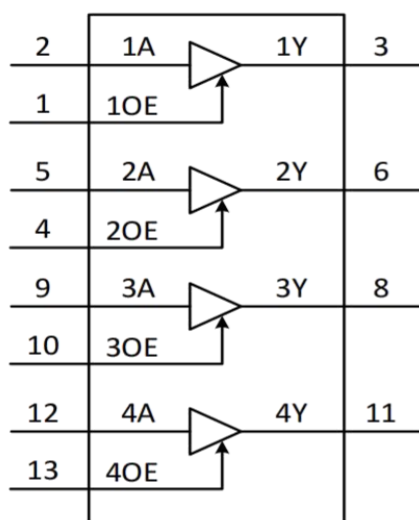


Fig. 1. Logic symbol

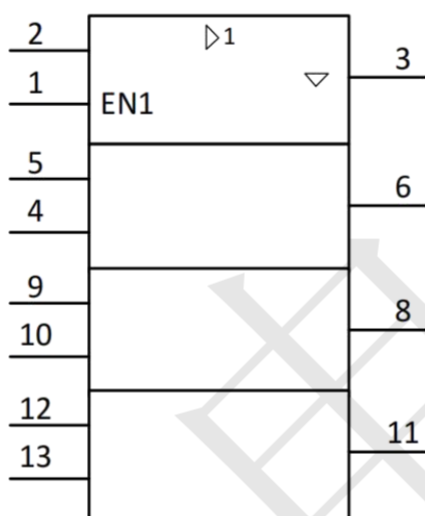


Fig. 2. IEC logic symbol

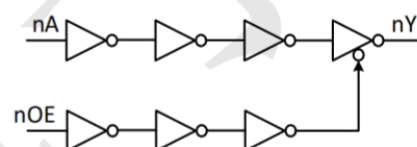


Fig. 3. Logic diagram(one gate)

Functional Description

Function table

Input		Output
nOE	nA	nY
H	L	L
H	H	H
L	X	Z

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

ABSOLUTE MAXIMUM RATINGS

In accordance with the Absolute Maximum Rating System. Voltages are referenced to GND.

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	7.0	V
I_{IK}	input clamping current	$V_I < 0\text{ V}$	-50	--	mA
V_I	input voltage	(1)	-0.5	7.0	V
I_{OK}	output clamping current	$V_O > V_{CC}$ or $V_O < 0\text{ V}$	--	± 50	mA
V_O	output voltage	Active mode (1)	0	$V_{CC} + 0.5$	V
		Power-down mode; $V_{CC} = 0\text{ V}$ (1)	0	7.0	V
I_O	output current	$V_O = 0\text{ V}$ to V_{CC}	--	± 50	mA
I_{CC}	supply current		--	100	mA
I_{GND}	ground current		-100	--	mA
P_{tot}	total power dissipation	$T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$	--	500	mW
T_{stg}	storage temperature		-65	150	$^{\circ}\text{C}$

Note:1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		2.0	5.5	V
		functional	1.5	--	V
V_I	input voltage		0	5.5	V
V_O	output voltage	Active mode	0	V_{CC}	V
		Power-down mode; $V_{CC} = 0\text{ V}$	0	5.5	V
T_{amb}	ambient temperature		-40	125	$^{\circ}\text{C}$
$\Delta t/\Delta V$	Input transition rise and fall rate	$V_{CC} = 2.0\text{ V}$ to 2.7 V	0	20	ns/V
		$V_{CC} = 2.7\text{ V}$ to 5.5 V	0	10	ns/V

Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	
V_{IH}	HIGH-level input voltage	$V_{CC} = 2.0 \text{ V}$	$0.65V_{CC}$	--	--	$0.65V_{CC}$	--	V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7	--	--	1.7	--	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2.0	--	--	2.0	--	V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	$0.7V_{CC}$	--	--	$0.7V_{CC}$	--	V
V_{IL}	LOW-level input voltage	$V_{CC} = 2.0 \text{ V}$	--	--	$0.35V_{CC}$	--	$0.35V_{CC}$	V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	--	--	0.7	--	0.7	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	--	--	0.8	--	0.8	V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	--	--	$0.3V_{CC}$	--	$0.3V_{CC}$	V
V_{OH}	HIGH-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}$						
		$I_O = -100\mu\text{A}; V_{CC} = 2.0 \text{ V to } 5.5 \text{ V}$	$V_{CC} - 0.1$	--	--	$V_{CC} - 0.1$	--	V
		$I_O = -4 \text{ mA}; V_{CC} = 2.0 \text{ V}$	1.5	--	--	1.25	--	V
		$I_O = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	--	--	1.7	--	V
		$I_O = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	2.2	--	--	2.05	--	V
		$I_O = -24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.4	--	--	2.25	--	V
		$I_O = -32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.8	--	--	3.5	--	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}$						
		$I_O = 100\mu\text{A}; V_{CC} = 2.0 \text{ V to } 5.5 \text{ V}$	--	--	0.10	--	0.10	V
		$I_O = 4 \text{ mA}; V_{CC} = 2.0 \text{ V}$	--	--	0.45	--	0.65	V
		$I_O = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	--	--	0.30	--	0.45	V
		$I_O = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	--	--	0.40	--	0.60	V
		$I_O = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	--	--	0.55	--	0.80	V
		$I_O = 32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	--	--	0.55	--	0.80	V
I_I	Input leakage current	$V_I = 5.5 \text{ V or GND}; V_{CC} = 0 \text{ V to } 5.5 \text{ V}$	--	± 0.1	± 5	--	± 20	μA

Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	
I_{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 5.5V$; $V_O = 5.5V$ or GND	--	± 0.1	± 5	--	± 20	μA
I_{OFF}	power-off leakage current	$V_{CC} = 0V$; V_I or $V_O = 5.5 V$	--	± 0.1	± 10	--	± 20	μA
I_{CC}	supply current	$V_I = 5.5V$ or GND ; $I_O = 0A$; $V_{CC} = 2.0V$ to $5.5V$	--	0.01	10	--	40	μA
ΔI_{CC}	additional supply current	per input pin ; $V_{CC} = 2.3V$ to $5.5V$; $V_I = V_{CC} - 0.6V$; $I_O = 0A$	--	0.2	500	--	5000	μA
C_I	input capacitance	$V_{CC} = 3.3V$; $V_I = GND$ to V_{CC}	--	4	--	--	--	pF

Note: All typical values are measured at $V_{CC} = 3.3V$ and $T_{amb} = 25\text{ }^{\circ}C$.

Dynamic Characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	
t_{pd}	propagation delay	nA to nY;						
		$V_{CC} = 2.0 V$	3.0	7.9	16.2	3.0	16.5	ns
		$V_{CC} = 2.3 V$ to $2.7 V$	2.2	4.4	8.0	2.2	8.6	ns
		$V_{CC} = 3.0 V$ to $3.6 V$	1.5	3.4	5.8	1.5	6.0	ns
		$V_{CC} = 4.5 V$ to $5.5 V$	1.1	2.6	4.0	1.1	4.5	ns

Dynamic Characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	
t_{en}	enable time	nOE to nY						
		$V_{CC} = 2.0V$	3.0	8.0	15.5	3.0	15.7	ns
		$V_{CC} = 2.3 V \text{ to } 2.7 V$	2.2	4.8	8.0	2.2	8.2	ns
		$V_{CC} = 3.0 V \text{ to } 3.6 V$	1.5	3.4	5.8	1.5	6.0	ns
		$V_{CC} = 4.5 V \text{ to } 5.5 V$	0.6	2.8	4.0	0.6	4.5	ns
t_{dis}	disable time	nOE to nY						
		$V_{CC} = 2.0 V$	2.0	7.2	15.5	2.0	15.7	ns
		$V_{CC} = 2.3 V \text{ to } 2.7 V$	1.6	5.7	8.6	1.6	8.8	ns
		$V_{CC} = 3.0 V \text{ to } 3.6 V$	1.3	4.5	6.5	1.3	7.0	ns
		$V_{CC} = 4.5 V \text{ to } 5.5 V$	0.4	2.7	4.5	0.4	5.0	ns
C_{PD}	power dissipation capacitance	per buffer ; $V_I = GND \text{ to } V_{CC}$						
		$V_{CC} = 2.0 V$	--	12	--	--	--	pF
		$V_{CC} = 2.3 V \text{ to } 2.7 V$	--	13	--	--	--	pF
		$V_{CC} = 3.0 V \text{ to } 3.6 V$	--	14	--	--	--	pF
		$V_{CC} = 4.5 V \text{ to } 5.5 V$	--	16	--	--	--	pF
$t_{sk(o)}$	output skew time	$V_{CC} = 3.0 V \text{ to } 3.6 V$	--	--	1.0	--	1.5	ns

Note:

Typical values are measured at $T_{amb} = 25^\circ C$ and $V_{CC} = 2.0 V, 2.5 V, 3.3 V$ and $5.0 V$ respectively.

t_{pd} is the same as t_{PLH} and t_{PHL} .

Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

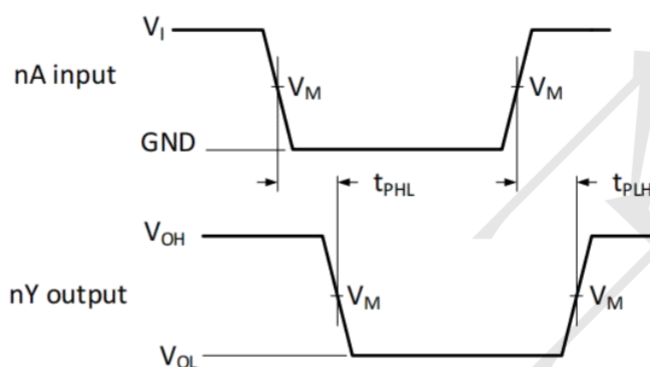
C_L = output load capacitance in

pF; V_{CC} = supply voltage in V;

N = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

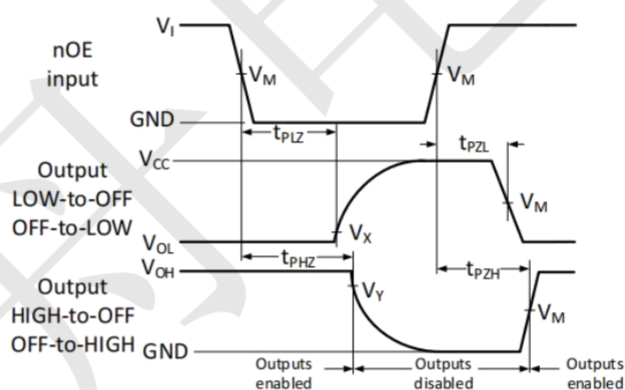
Waveforms and test circuit



Measurement points are given in Table 8.

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 5. The input nA to output nY propagation delays



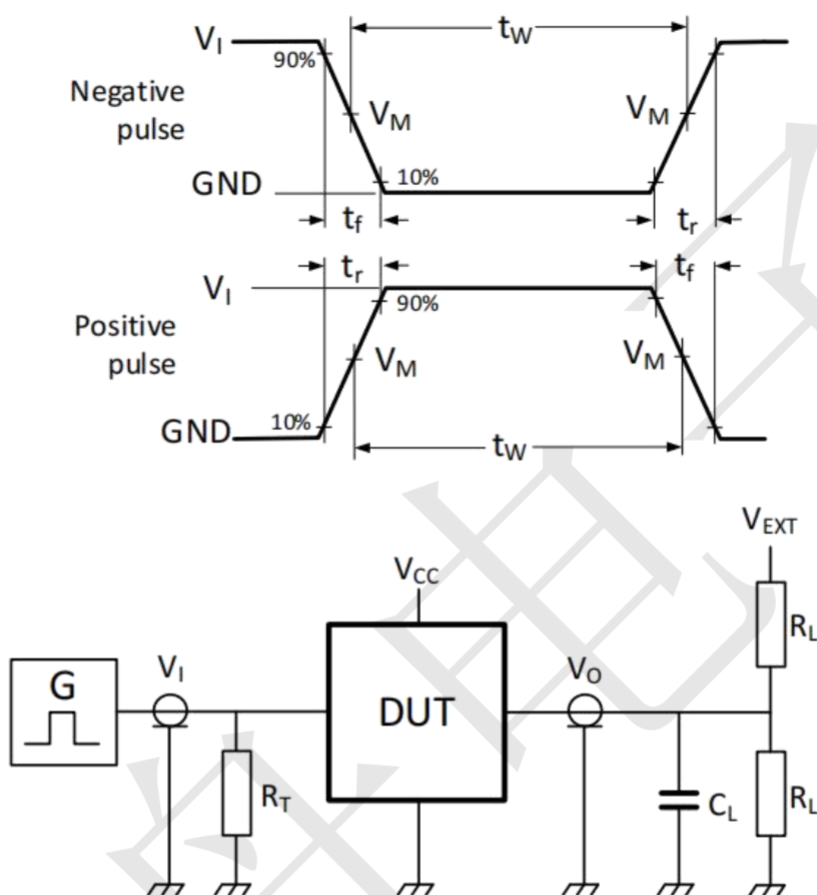
Measurement points are given in Table 8.

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 6. 3-state enable and disable times

Measurement points

Supply voltage	Input	Output		
V_{CC}	V_M	V_M	V_X	V_Y
2.0 V	$0.5V_{CC}$	$0.5V_{CC}$	$V_{OL} + 0.15V$	$V_{OH} - 0.15V$
2.3 V to 2.7 V	$0.5V_{CC}$	$0.5V_{CC}$	$V_{OL} + 0.15V$	$V_{OH} - 0.15V$
3.0 V to 3.6 V	1.5 V	1.5 V	$V_{OL} + 0.3V$	$V_{OH} - 0.3V$
4.5 V to 5.5 V	$0.5V_{CC}$	$0.5V_{CC}$	$V_{OL} + 0.3V$	$V_{OH} - 0.3V$



Test data is given in Table 9.

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

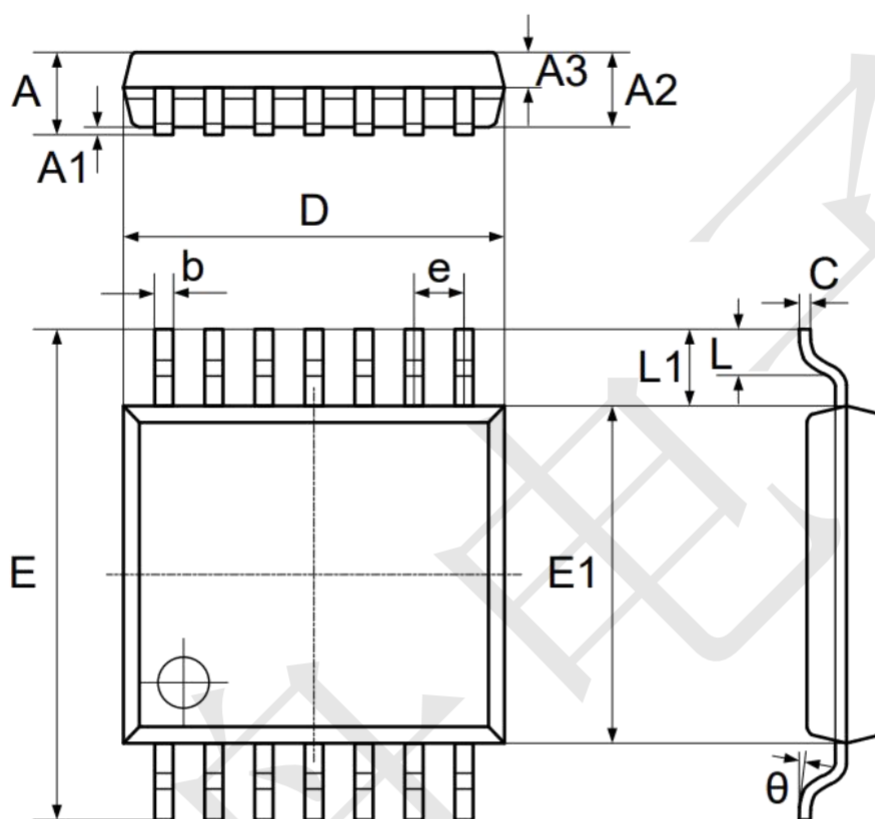
V_{EXT} = External voltage for measuring switching times.

Fig. 7. Test circuit for measuring switching times

Test data

Supply voltage	Input		Load		V_{EXT}		
V_{CC}	V_I	$t_r = t_f$	C_L	R_L	t_{PLH}, t_{PHL}	t_{PZH}, t_{PHZ}	t_{PZL}, t_{PLZ}
2.0 V	V_{CC}	≤ 2.0 ns	15 pF	500 Ω	open	GND	$2 \times V_{CC}$
2.3 V to 2.7 V	V_{CC}	≤ 2.0 ns	15 pF	500 Ω	open	GND	$2 \times V_{CC}$
3.0 V to 3.6 V	3 V	≤ 2.0 ns	15 pF	500 Ω	open	GND	6V
4.5 V to 5.5 V	V_{CC}	≤ 2.0 ns	15 pF	500 Ω	open	GND	$2 \times V_{CC}$

Package information TSSOP-14



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	-	1.200	-	0.047
A1	0.050	0.150	0.002	0.006
A2	0.900	1.050	0.035	0.041
A3	0.390	0.490	0.015	0.019
b	0.200	0.290	0.008	0.011
C	0.130	0.180	0.005	0.007
D	4.860	5.060	0.191	0.199
E	6.200	6.600	0.244	0.260
E1	4.300	4.500	0.169	0.177
e	0.650 TYP.		0.026 TYP.	
L1	1.000 REF.		0.039 REF.	
L	0.450	0.750	0.018	0.030
θ	0°	8°	0°	8°